

# NTST20U100CT, NTSB20U100CT-1G, NTSJ20U100CTG, NTSB20U100CTG

## Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low  $V_F = 0.50\text{ V}$  at  $I_F = 5\text{ A}$

### Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- Pb-Free and Halide-Free Packages are Available

### Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

### Mechanical Characteristics

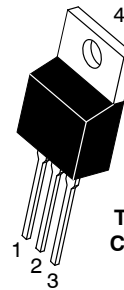
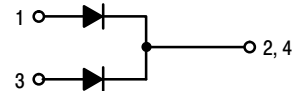
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



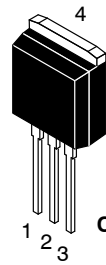
ON Semiconductor®

<http://onsemi.com>

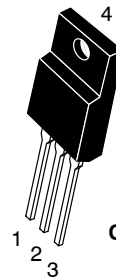
### PIN CONNECTIONS



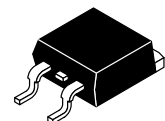
TO-220AB  
CASE 221A  
STYLE 6



I2PAK  
CASE 418D  
STYLE 3



TO-220FP  
CASE 221AH



D2PAK  
CASE 418B

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# NTST20U100CT, NTSB20U100CT-1G, NTSJ20U100CTG, NTSB20U100CTG

## MAXIMUM RATINGS

| Rating                                                                                                                        | Symbol                          | Value       | Unit             |
|-------------------------------------------------------------------------------------------------------------------------------|---------------------------------|-------------|------------------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                        | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | 100         | V                |
| Average Rectified Forward Current<br>(Rated $V_R$ , $T_C = 130^\circ\text{C}$ )<br>Per device<br>Per diode                    | $I_{F(AV)}$                     | 20<br>10    | A                |
| Peak Repetitive Forward Current<br>(Rated $V_R$ , Square Wave, 20 kHz, $T_C = 125^\circ\text{C}$ )<br>Per device<br>Per diode | $I_{FRM}$                       | 40<br>20    | A                |
| Nonrepetitive Peak Surge Current<br>(Surge applied at rated load conditions halfwave, single phase, 60 Hz)                    | $I_{FSM}$                       | 150         | A                |
| Operating Junction Temperature                                                                                                | $T_J$                           | -40 to +150 | $^\circ\text{C}$ |
| Storage Temperature                                                                                                           | $T_{stg}$                       | -40 to +150 | $^\circ\text{C}$ |
| Voltage Rate of Change (Rated $V_R$ )                                                                                         | $dv/dt$                         | 10,000      | V/ $\mu\text{s}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## THERMAL CHARACTERISTICS

| Rating                                                                          | Symbol                             | NTST20U100CTG,<br>NTSB20U100CT-1G | NTSB20U100CTG | NTSJ20U100CTG | Unit                                     |
|---------------------------------------------------------------------------------|------------------------------------|-----------------------------------|---------------|---------------|------------------------------------------|
| Maximum Thermal Resistance per Diode<br>Junction-to-Case<br>Junction-to-Ambient | $R_{\theta JC}$<br>$R_{\theta JA}$ | 2.5<br>70                         | 1.24<br>46.7  | 4.20<br>105   | $^\circ\text{C/W}$<br>$^\circ\text{C/W}$ |

## ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

| Rating                                                                                                                                                                                                                                                                     | Symbol | Typ                              | Max                        | Unit                                           |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|----------------------------------|----------------------------|------------------------------------------------|
| Maximum Instantaneous Forward Voltage (Note 1)<br>( $I_F = 5\text{ A}$ , $T_J = 25^\circ\text{C}$ )<br>( $I_F = 10\text{ A}$ , $T_J = 25^\circ\text{C}$ )<br><br>( $I_F = 5\text{ A}$ , $T_J = 125^\circ\text{C}$ )<br>( $I_F = 10\text{ A}$ , $T_J = 125^\circ\text{C}$ ) | $V_F$  | 0.55<br>0.65<br><br>0.50<br>0.58 | –<br>0.79<br><br>–<br>0.68 | V                                              |
| Maximum Instantaneous Reverse Current (Note 1)<br>( $V_R = 70\text{ V}$ , $T_J = 25^\circ\text{C}$ )<br>( $V_R = 70\text{ V}$ , $T_J = 125^\circ\text{C}$ )<br><br>(Rated dc Voltage, $T_J = 25^\circ\text{C}$ )<br>(Rated dc Voltage, $T_J = 125^\circ\text{C}$ )         | $I_R$  | 17<br>5.3<br><br>–<br>12         | –<br>–<br><br>800<br>25    | $\mu\text{A}$<br>mA<br><br>$\mu\text{A}$<br>mA |

1. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

TYPICAL CHARACTERISTICS

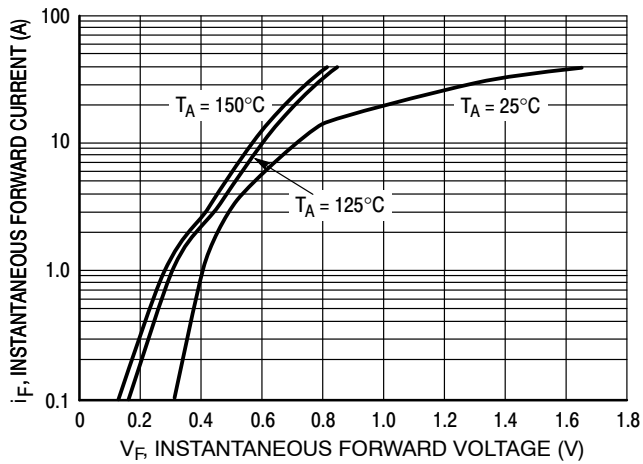


Figure 1. Typical Instantaneous Forward Characteristics

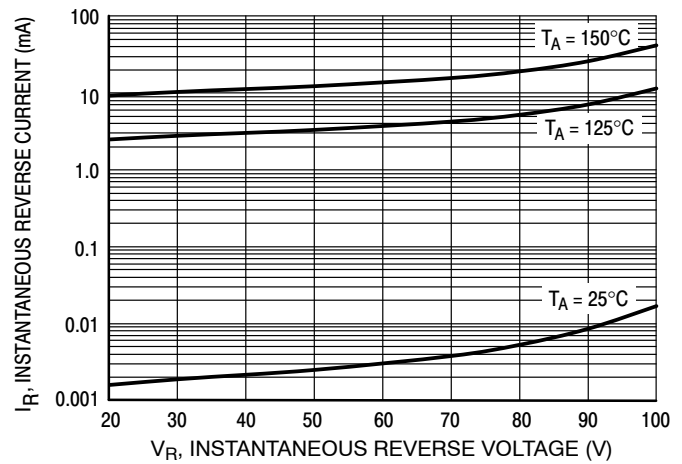


Figure 2. Typical Reverse Characteristics

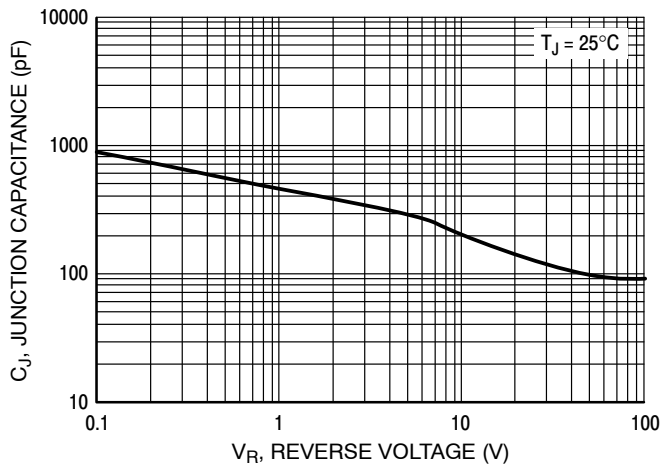


Figure 3. Typical Junction Capacitance

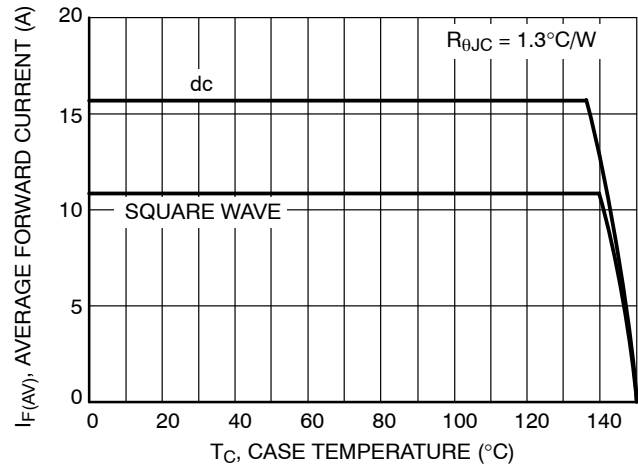


Figure 4. Current Derating per Leg

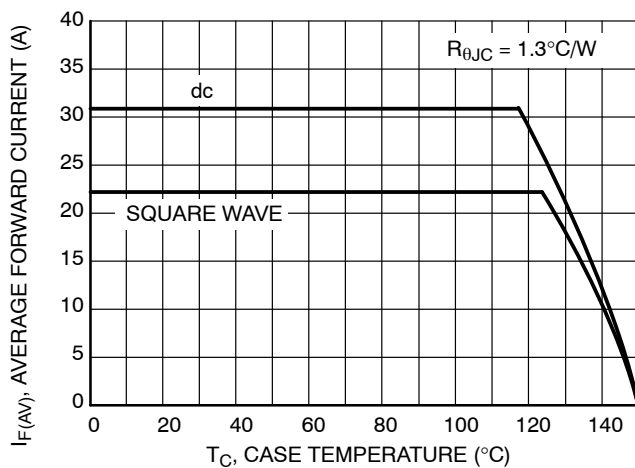


Figure 5. Current Derating

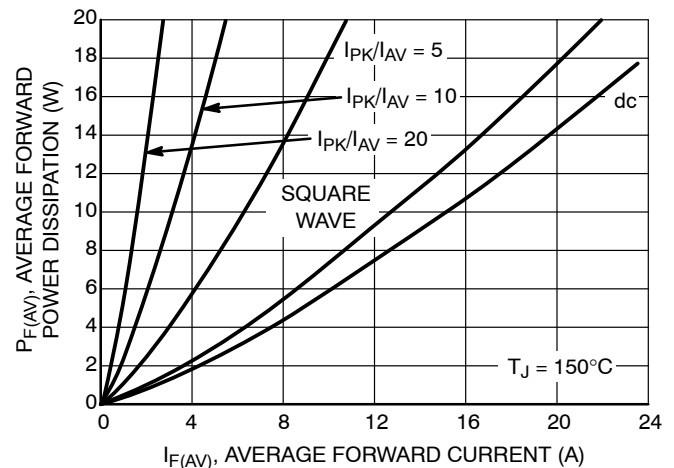


Figure 6. Forward Power Dissipation

TYPICAL CHARACTERISTICS

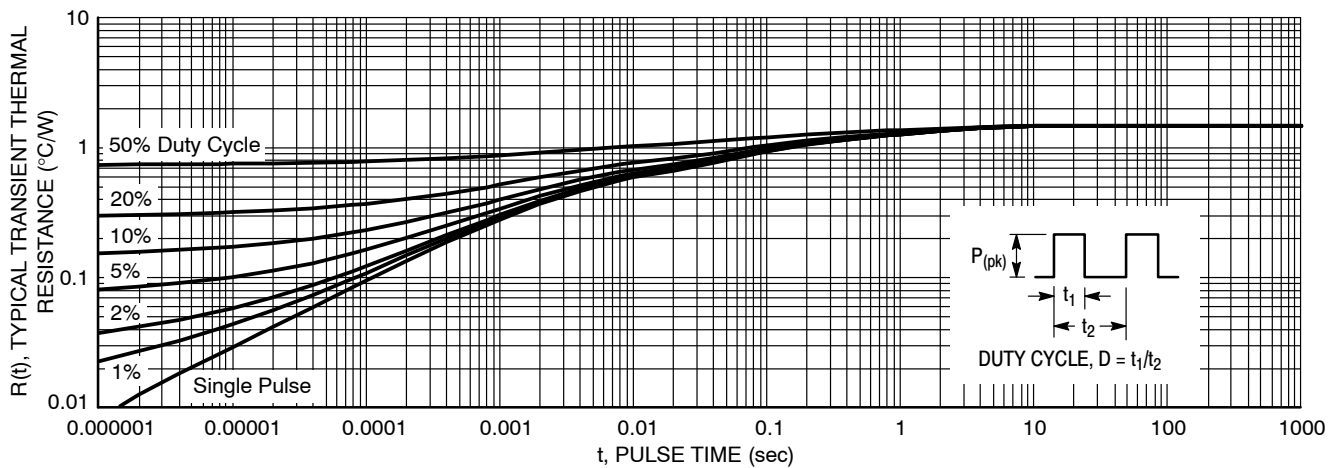


Figure 7. Typical Transient Thermal Response for NTST20U100CT and NTSB20U100CT-1G

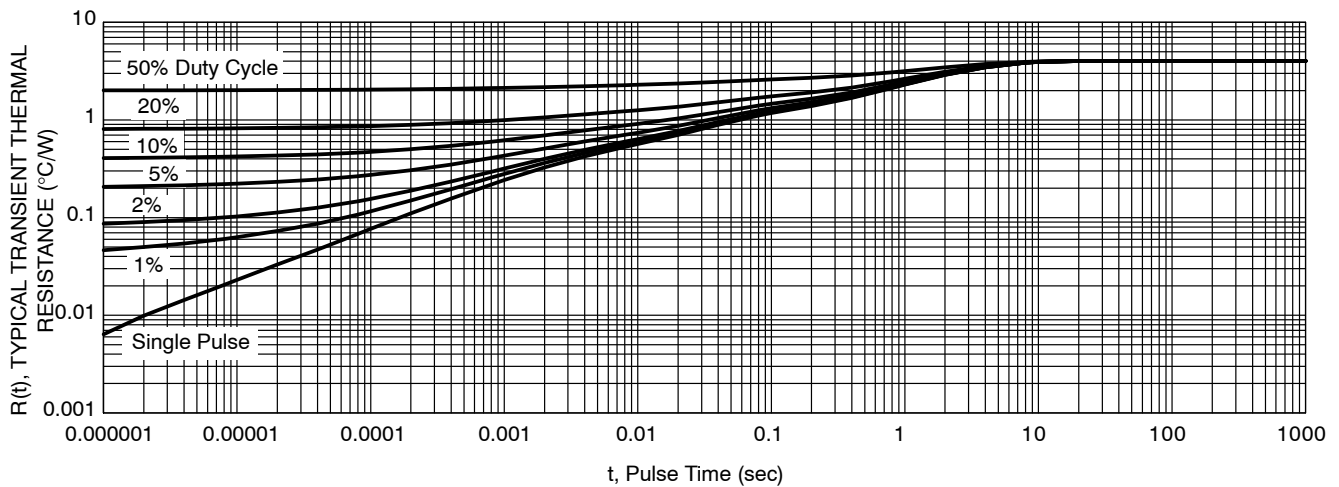


Figure 8. Typical Transient Thermal Response, Junction-to-Case for NTSJ20U100CTG

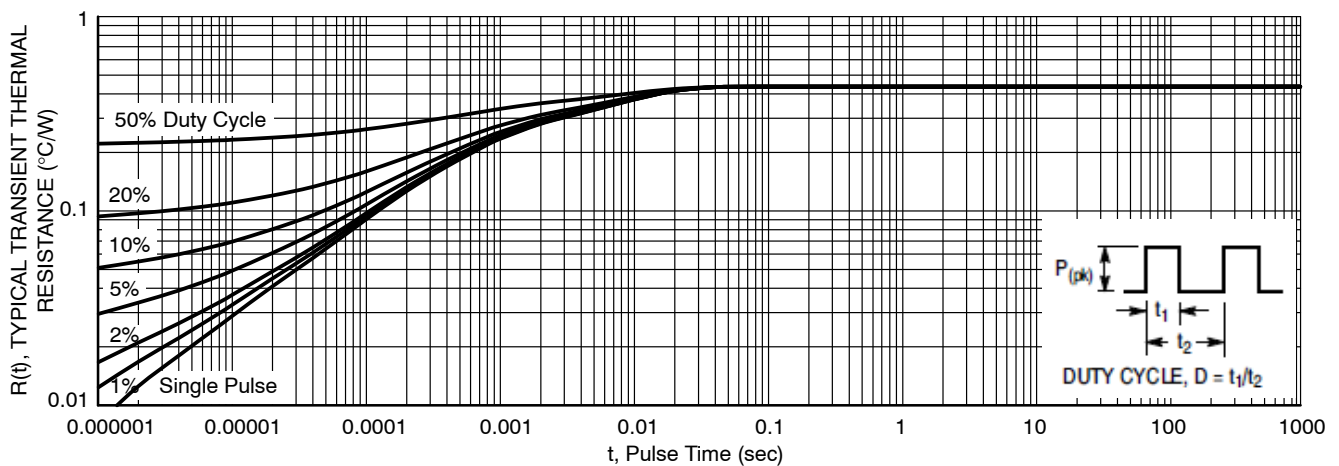


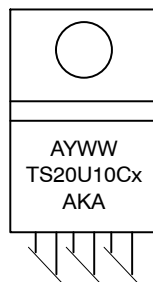
Figure 9. Typical Transient Thermal Response for NTSB20U100CTG

# NTST20U100CT, NTSB20U100CT-1G, NTSJ20U100CTG, NTSB20U100CTG

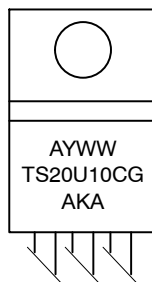
## ORDERING INFORMATION

| Device          | Package                         | Shipping          |
|-----------------|---------------------------------|-------------------|
| NTST20U100CTG   | TO-220AB<br>(Pb-Free)           | 50 Units / Rail   |
| NTSB20U100CT-1G | I <sup>2</sup> PAK<br>(Pb-Free) | 50 Units / Rail   |
| NTSJ20U100CTG   | TO-220FP<br>(Halide-Free)       | 50 Units / Rail   |
| NTSB20U100CTG   | D <sup>2</sup> PAK<br>(Pb-Free) | 50 Units / Rail   |
| NTSB20U100CTT4G | D <sup>2</sup> PAK<br>(Pb-Free) | 800 / Tape & Reel |

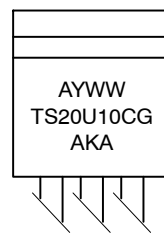
## MARKING DIAGRAMS



TO-220AB



TO-220FP



I<sup>2</sup>PAK

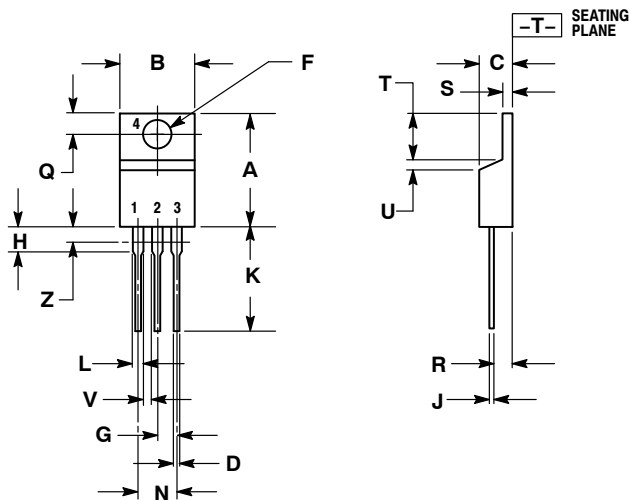


D<sup>2</sup>PAK

A = Assembly Location  
 Y = Year  
 WW = Work Week  
 AKA = Polarity Designator  
 x = G or H  
 G = Pb-Free Package  
 H = Halide-Free Package

PACKAGE DIMENSIONS

TO-220  
CASE 221A-09  
ISSUE AF

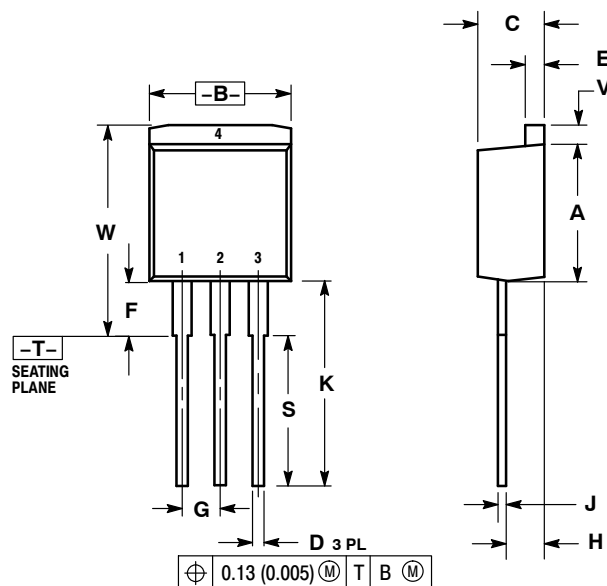


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

| DIM | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
|     | MIN    | MAX   | MIN         | MAX   |
| A   | 0.570  | 0.620 | 14.48       | 15.75 |
| B   | 0.380  | 0.405 | 9.66        | 10.28 |
| C   | 0.160  | 0.190 | 4.07        | 4.82  |
| D   | 0.025  | 0.035 | 0.64        | 0.88  |
| F   | 0.142  | 0.161 | 3.61        | 4.09  |
| G   | 0.095  | 0.105 | 2.42        | 2.66  |
| H   | 0.110  | 0.155 | 2.80        | 3.93  |
| J   | 0.014  | 0.025 | 0.36        | 0.64  |
| K   | 0.500  | 0.562 | 12.70       | 14.27 |
| L   | 0.045  | 0.060 | 1.15        | 1.52  |
| N   | 0.190  | 0.210 | 4.83        | 5.33  |
| Q   | 0.100  | 0.120 | 2.54        | 3.04  |
| R   | 0.080  | 0.110 | 2.04        | 2.79  |
| S   | 0.045  | 0.055 | 1.15        | 1.39  |
| T   | 0.235  | 0.255 | 5.97        | 6.47  |
| U   | 0.000  | 0.050 | 0.00        | 1.27  |
| V   | 0.045  | ---   | 1.15        | ---   |
| Z   | ---    | 0.080 | ---         | 2.04  |

- STYLE 6:
1. ANODE
  2. CATHODE
  3. ANODE
  4. CATHODE

I<sup>2</sup>PAK (TO-262)  
CASE 418D  
ISSUE D

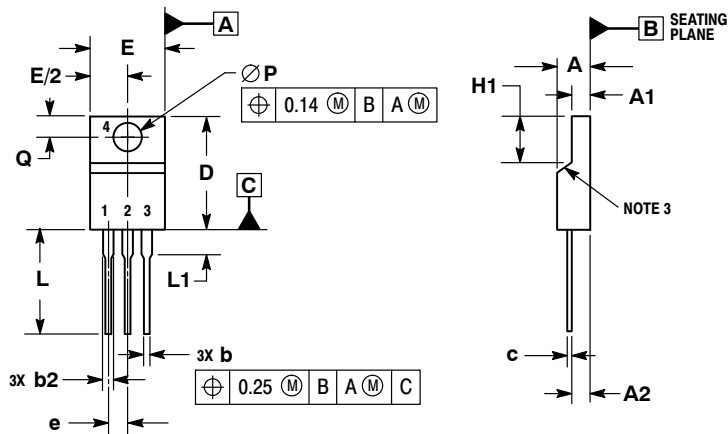


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES    |       | MILLIMETERS |       |
|-----|-----------|-------|-------------|-------|
|     | MIN       | MAX   | MIN         | MAX   |
| A   | 0.335     | 0.380 | 8.51        | 9.65  |
| B   | 0.380     | 0.406 | 9.65        | 10.31 |
| C   | 0.160     | 0.185 | 4.06        | 4.70  |
| D   | 0.026     | 0.035 | 0.66        | 0.89  |
| E   | 0.045     | 0.055 | 1.14        | 1.40  |
| F   | 0.122 REF |       | 3.10 REF    |       |
| G   | 0.100 BSC |       | 2.54 BSC    |       |
| H   | 0.094     | 0.110 | 2.39        | 2.79  |
| J   | 0.013     | 0.025 | 0.33        | 0.64  |
| K   | 0.500     | 0.562 | 12.70       | 14.27 |
| L   | 0.390 REF |       | 9.90 REF    |       |
| M   | 0.045     | 0.070 | 1.14        | 1.78  |
| N   | 0.522     | 0.551 | 13.25       | 14.00 |

PACKAGE DIMENSIONS

TO-220 FULLPACK, 3-LEAD  
CASE 221AH  
ISSUE B



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR UNCONTROLLED IN THIS AREA.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

| DIM | MILLIMETERS |       |
|-----|-------------|-------|
|     | MIN         | MAX   |
| A   | 4.30        | 4.70  |
| A1  | 2.50        | 2.90  |
| A2  | 2.50        | 2.70  |
| b   | 0.54        | 0.84  |
| b2  | 1.10        | 1.40  |
| c   | 0.49        | 0.79  |
| D   | 14.70       | 15.30 |
| E   | 9.70        | 10.30 |
| e   | 2.54 BSC    |       |
| H1  | 6.70        | 7.10  |
| L   | 12.70       | 14.73 |
| L1  | ---         | 2.80  |
| P   | 3.00        | 3.40  |
| Q   | 2.80        | 3.20  |





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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**Факс:** 8 (812) 320-02-42

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